NSN 5961-01-339-4250

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-339-4250 **Inclosure Material:** Metal and plastic **Overall Length:** 15.1 millimeters **Terminal Length:** Between 12.70 millimeters and 14.73 millimeters **Overall Height:** 4.82 millimeters **Overall Width:** 10.5 millimeters **Function For Which Designed:** Rectifier **End Application:** Tactical air operations central an/tyq-2 (v) 1 **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ac **Mounting Method:** Terminal and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 working peak reverse voltage **Current Rating Per Characteristic:** 10.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No Fiig:

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